TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC151AP,TC74HC151AF,TC74HC151AFN

8-Channel Multiplexer

The TC74HC151A is a high speed CMOS 8-CHANNEL MULTIPLEXER fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

One of eight date input signals (D0-D7) is selected by decoding of the three-bit address input (A, B, C). The selected data appears on two outputs: non-inverting (Y) and inverting (W).

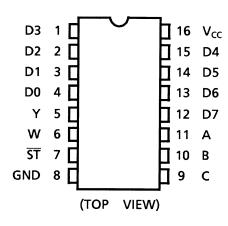
The strobe input provides two output conditions; a low level on the strobe input transfers the selected data to the outputs. A high level on the strobe input sets the Y output low and the W output high without regard to the data or select input conditions.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

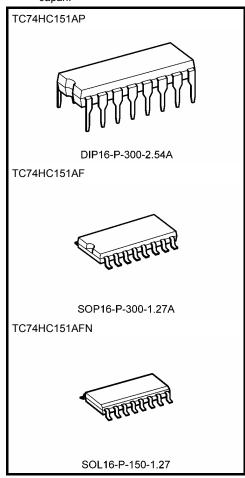
Features

- High speed: $t_{pd} = 15 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 4 \text{ mA (min)}$
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: VCC (opr) = 2 to 6 V
- Pin and function compatible with 74LS151

Pin Assignment



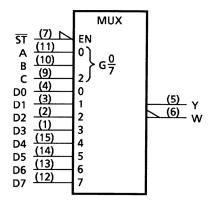
Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.) SOL16-P-150-1.27 : 0.13 g (typ.)

IEC Logic Symbol



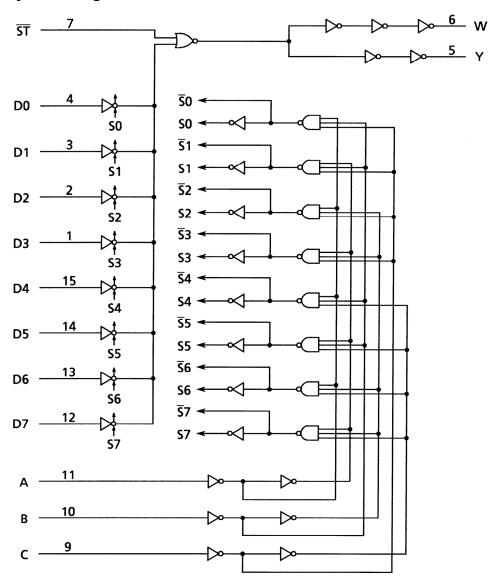
Truth Table

	I	Outputs			
Select			Strobe	V	W
С	В	Α	ST	Y	VV
Х	Х	Х	Н	L	Н
L	L	L	L	D0	D0
L	L	Н	L	D1	D ₁
L	Н	L	L	D2	D ₂
L	Н	Н	L	D3	D3
Н	L	L	L	D4	D̄4
Н	L	Н	L	D5	D ₅
Н	Н	L	L	D6	D̄6
Н	Н	Н	L	D7	D7

X: Don't care

2

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	–0.5 to 7	V
DC input voltage	V _{IN}	−0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	−0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	I _{CC}	±50	mA
Power dissipation	P_{D}	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65° C. From Ta = 65 to 85° C a derating factor of -10 mW/°C shall be applied until 300 mW.

3



Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2 to 6	V
Input voltage	V _{IN}	0 to V _{CC}	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
		0 to 1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns
		0 to 400 (V _{CC} = 6.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics Symbol		Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
	,			V _{CC} (V)	Min	Тур.	Max	Min	Max	
		_		2.0	1.50	_	_	1.50	_	
High-level input voltage	V_{IH}			4.5	3.15	_	_	3.15	_	V
Ŭ				6.0	4.20			4.20	_	
				2.0	_	_	0.50	_	0.50	
Low-level input voltage	V_{IL}	_		4.5	_	_	1.35	_	1.35	V
Ŭ				6.0	_		1.80	_	1.80	
	Vон	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_	
			I _{OH} = -20 μA	4.5	4.4	4.5	_	4.4	_	
High-level output voltage				6.0	5.9	6.0	_	5.9	_	V
Ŭ			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
	V _{OL}	V _{IN} = V _{IH} or V _{IL}		2.0	_	0.0	0.1	_	0.1	
			$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1	_	0.1	
Low-level output voltage				6.0	_	0.0	0.1	_	0.1	V
			I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33	
			$I_{OL} = 5.2 \text{ mA}$	6.0	_	0.18	0.26	_	0.33	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	_		±0.1	_	±1.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		6.0		_	4.0	_	40.0	μА



AC Characteristics (C_L = 15 pF, V_{CC} = 5 V, Ta = 25°C, input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t _{TLH}			4	8	ns
Output transition time	t _{THL}	_		7	O	113
Propagation delay time	t _{pLH}			15	24	ns
(D-Y)	t _{pHL}	_	_			115
Propagation delay time	t _{pLH}			15	24	ns
(D-W)	t _{pHL}	_	_	13	24	115
Propagation delay time	t _{pLH}			10	17	ns
(ST-Y)	t _{pHL}	_	_	10	17	115
Propagation delay time	t _{pLH}			10	17	no
(ST-W)	t _{pHL}	_	_	10	17	ns
Propagation delay time	t _{pLH}			19	31	no
(A, B, C-Y)	t _{pHL}	_		19	31	ns
Propagation delay time	t _{pLH}			19	31	no
(A, B, C-W)	t _{pHL}	_		18	31	ns

5



AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C		Unit	
	,		V _{CC} (V)	Min	Тур.	Max	Min	Max	
			2.0	_	30	75	_	95	
Output transition time	t _{TLH}	_	4.5	_	8	15	_	19	ns
	t _{THL}		6.0	_	7	13	_	16	
Propagation delay	t _{pLH}		2.0		65	140	_	175	
time	t _{pHL}	_	4.5	_	18	28	_	35	ns
(D-Y)	γпс		6.0	_	15	24	_	30	
Propagation delay	t _{pLH}		2.0	_	65	140	_	175	
time		_	4.5	_	18	28	_	35	ns
(D-W)	t _{pHL}		6.0		15	24		30	
Propagation delay	t _{pLH}		2.0		36	100	_	125	
time —	t _{pHL}	_	4.5	_	12	20	_	25	ns
(ST-Y)	φпь		6.0		10	17	_	21	
Propagation delay	t _{pLH}		2.0	_	36	100	_	125	
time —	t _{pHL}	_	4.5	_	12	20	_	25	ns
(ST-W)	φпь		6.0	_	10	17	_	21	
Propagation delay	t _{pLH}		2.0	_	80	180	_	225	
time	t _{pHL}	_	4.5	_	23	36	_	45	ns
(A, B, C-Y)	φн∟		6.0		19	31		38	
Propagation delay	t _{pLH}		2.0	_	80	180	_	225	
time	t _{pHL}	_	4.5	_	23	36	_	45	ns
(A, B, C-W)	чрнь		6.0	_	19	31	_	38	
Input capacitance	C _{IN}	_			5	10		10	pF
Power dissipation capacitance	C _{PD} (Note)			_	69	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

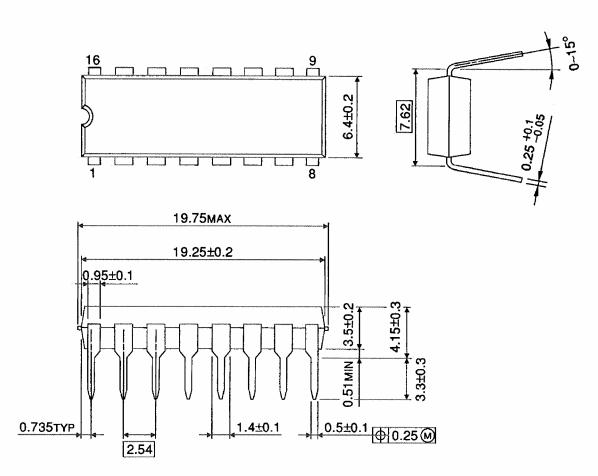
6

Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

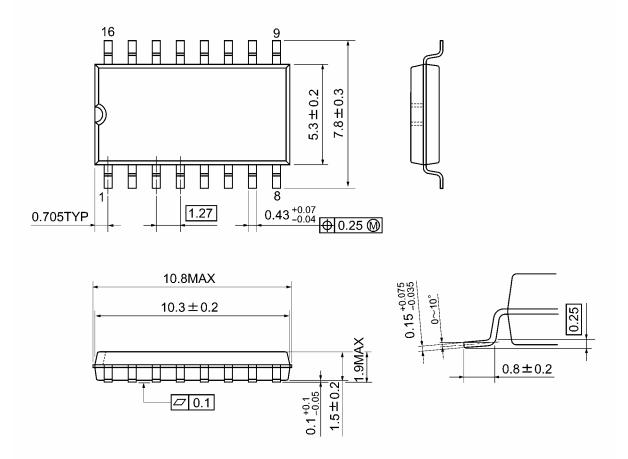
DIP16-P-300-2.54A Unit: mm



Weight: 1.00 g (typ.)

Package Dimensions

SOP16-P-300-1.27A Unit: mm

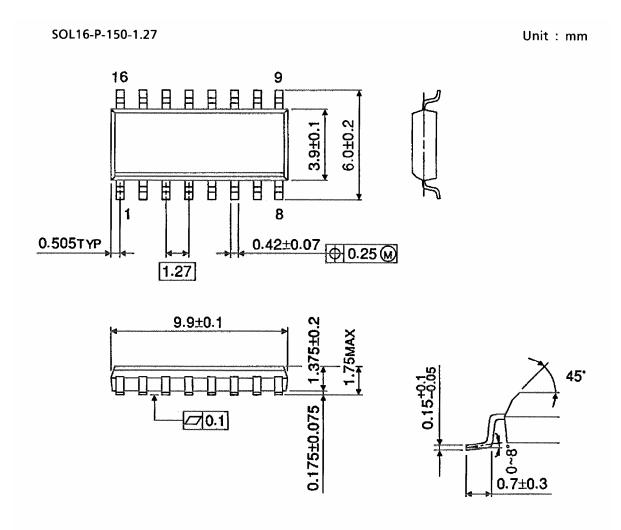


8

Weight: 0.18 g (typ.)



Package Dimensions (Note)



9

Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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20070701-EN GENERAL

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